

Low Side µPower Current Sense Amplifier

Introduction

The ISL28133CSENSEV1Z evaluation board is designed specifically for low side current sensing up to 10A of current. The evaluation board uses a $1 m \Omega$ current sense resistor that is capable of handling 4W of power dissipation. The ISL28133 micropower Zero Drift Amplifier gains the current sensing input signal and can be used to directly drive ADC inputs.

The ISL28133CSENSEV1Z evaluation board is optimized to operate at +5V. An ISL21070 micropower 2.5V voltage reference sets a zero current reading of 2.5V at the amplifier output to interface with ADCs operating at 5V. The voltage reference raises the common mode input by approximately 40mV above GND at zero current flow. This connection enables bi-directional current sensing, allowing the sense voltage to be positive or negative relative to the common mode voltage. This is helpful for applications such as the charging/discharging current from an Electric Vehicle battery or motors that switch polarity.

With the input common mode at 40mV above ground and a $1m\Omega$ sense resistor, this allows $\pm 40A$ current sensing before amplifier saturation. However, due to PCB copper resistance causing error at high currents, the recommended current sense is $\pm 10A$.

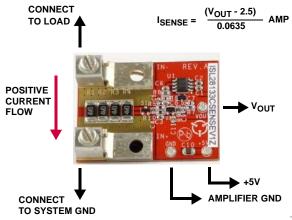


FIGURE 1. ISL28133CSENSEV1Z EVALUATION BOARD

Board Layout

The evaluation board is laid out with heavy duty screw lug terminals that allow connections of wires up to 6 AWG. The $1 m\Omega$ sense resistance is formed from four $4 m\Omega$ 2512 style resistors to increase power dissipation capacity of the sense circuitry. The total power dissipation critically allowed is 4W. The PCB board is made using 2oz copper PCB with the current path routed on the top and bottom layer, minimizing trace resistance to maintain accurate current sense resistance. To further reduce sense errors, the current sensing uses a Kelvin connection with the sense voltage pick up points at the center of the current density distribution.

Amplifier U3 gains up the voltage drop developed across the sense resistor from the current flow. Voltage Reference U2 sets the zero current reading output of the amplifier at 2.5V.

Quick Setup Guide

- 1. Connect single supply +5VDC to +5V and GND terminals.
- 2. Connect low side load to terminal lugs. Current flow from top to bottom of board.
- 3. At no load, V_{OUT} is 2.5V.
- With 1mΩ sense resistance and amplifier gain of 63.5V/V, the sense current reading is: (V_{OLIT} - 2.5V)/0.0635 in Amps.

| REF | PART NUMBER | COMMENTS |
|-----|-------------|-----------------------------------|
| U1 | DNP | Not Populated On Board |
| U2 | ISL21070 | Micropower 2.5V Voltage Reference |
| U3 | ISL28133 | Micropower Zero Drift Amplifier |

| CURRENT SENSE SPECIFICATIONS | | | | | |
|----------------------------------|--|--|--|--|--|
| Supply Voltage Range | 3.0V to 5.0V Optimized for 5V Operation | | | | |
| Max Sense Current | ±10A recommended | | | | |
| | ±40A Before Amplifier Saturation | | | | |
| Abs Max Sense Current | 60 Amps Thermally Limited by Sense Resistor | | | | |
| Current Sense Resolution | ±10mA | | | | |
| Current Sense Accuracy | 2% | | | | |
| Voltage to Current Conversion | I _{SENSE} = (V _{OUT} - 2.5V) / 0.0635 Amps | | | | |
| Amplifier Bandwidth | 6кHz | | | | |

Measuring Very High Current

The reference design is capable of sensing currents greater than $\pm 40A$, however, it is limited mechanically from the temperature rise of the copper PCB layout and current sense resistor and limited electrically by amplifier saturation. One must consider the temperature rise of the PCB trace from the power dissipated under high currents, which may cause the copper trace to delaminate. The high current carrying PCB trace is made with 2oz copper on FR4 board both top and bottom layers. The trace dimension is approximately 25mm width and 40mm length. Substantial vias are used to connect the planes for lower thermal impedance. The current sense resistance is capable of 4W dissipation max.

Application Note 1778

Bill of Materials

| PART NUMBER | REFERENCE DESIGNATOR | DESCRIPTION | MANUFACTURER | MANUFACTURER PART |
|----------------------|----------------------|--|------------------|-------------------|
| DNP | U1 | DO NOT POPULATE OR PURCHASE | | |
| ISL21070CIH325Z | U2 | Low Power 2.5V Voltage Reference, SOT23 | INTERSIL | ISL21070CIH325Z |
| ISL28133FHZ | U3 | Low Power Zero Drift Amplifier, SOT23 | INTERSIL | ISL28133FHZ |
| H1045-00101-50V5-T | C8, C9 | CAP, SMD, 0603, 100pF, 50V, 5%, COG, ROHS | GENERIC | |
| H1045-00102-50V5-T | C4 | CAP, SMD, 0603, 1000pF, 50V, 5%, COG, ROHS | GENERIC | |
| H1045-00103-50V10-T | C1, C3, C5, C6, C11 | CAP, SMD, 0603, 0.01µF, 50V, 10%, X7R, ROHS | GENERIC | |
| H1045-00104-50V10-T | C2 | CAP, SMD, 0603, 0.1µF, 50V, 10%, X7R, ROHS | GENERIC | |
| H1045-DNP | C7 | CAP, SMD, 0603, DNP-PLACE HOLDER, ROHS | | |
| H1065-00475-50V10-T | C10 | CAP, SMD, 1206, 4.7µF, 50V, 10%, X5R, ROHS | GENERIC | |
| BAV99LT1G-T | S1 | DIODE-SWITCHING, SMD, SOT23, 70V, 0.2A, ROHS | ON SEMICONDUCTOR | BAV99LT1G |
| H2511-00R00-1/10W-T | R7 | RES, SMD, 0603, 0Ω , 1/10W, TF, ROHS | GENERIC | |
| H2511-01623-1/10W1-T | R6, R9 | RES, SMD, 0603, 162k, 1/10W, 1%, TF, ROHS | GENERIC | |
| H2511-02551-1/10W1-T | R5, R10 | RES, SMD, 0603, 2.55k, 1/10W, 1%, TF, ROHS | GENERIC | |
| H2511-DNP | R8 | RES, SMD, 0603, DNP-PLACE HOLDER, ROHS | | |
| H2515-0R004-1W1-T | R1-R4 | RES, SMD, 2512, 0.004Ω, 1W, 1%, TF, ROHS | GENERIC | |

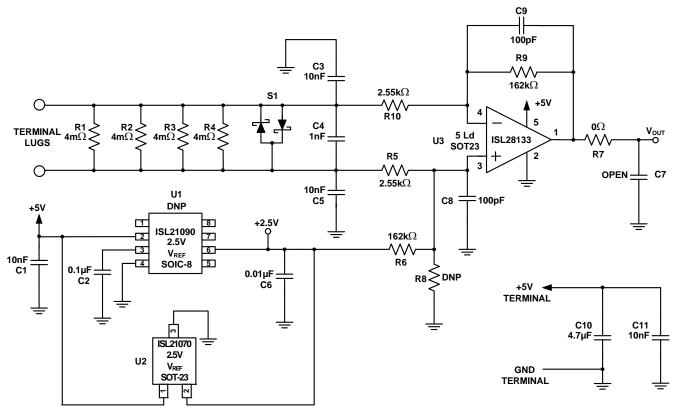


FIGURE 2. CURRENT SENSE AMPLIFIER SCHEMATIC

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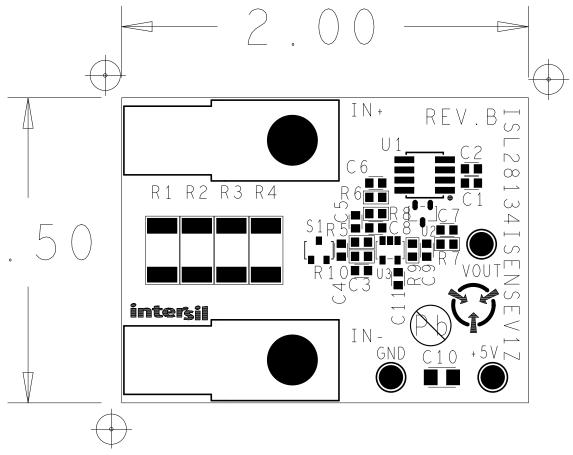
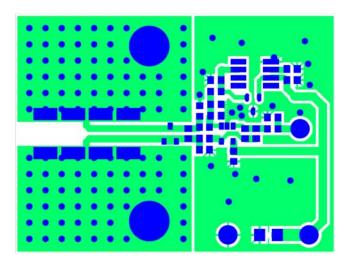


FIGURE 3. CURRENT SENSE AMPLIFIER ASSEMBLY DRAWING





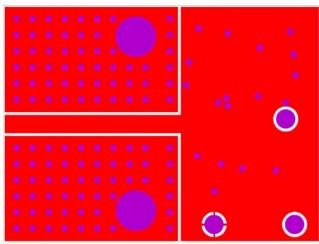


FIGURE 5. PCB BOTTOM LAYER

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